

MOS FET Relay

G3VM-W

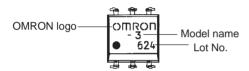
G3VM Low-cost Series (Two-output Models)

- New G3VM Series with 350-V-output dielectric strength.
- Two-output models now available.
- Approved Standards: UL1577



Ordering Information

■ Appearance



Note: "G3VM" is not printed on the actual product

■ Model Number Legend

G3VM-
$$\square$$

1. Load Voltage

W: Load voltage, 350 VDC or 350 VAC min.

2. Terminal

F: Surface-mounting terminals

None: PCB terminals

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick
DPST-NO	PCB terminals	350 VAC	G3VM-W-S	50
	Surface-mounting terminals		G3VM-WF-S	50

Specifications -

■ Absolute Maximum Ratings (Ta = 25°C)

		Item	Symbol	Rating	Unit
Input	LED forward curre	ent	I _F	50	mA
	LED forward curre	ent reduction rate (Ta≥25°C)	Δ I _F /°C	-0.5	mA/°C
	Repetitive peak LI	ED forward current (100 μs pulse)	I _{FP}	1	Α
	LED reverse voltage		V _R	5	V
	Connection temper	erature	T _i	125	°C
Output	Output dielectric	strength	V _{OFF}	350	V
	Continuous load current	Current per channel	I _O	120	mA
	ON current reduction rate (Ta≧25°C)	Current per channel	Δ I _{ON} /°C	-1.2	mA/°C
	Connection temper	erature	T _i	125	°C
Storage	temperature		T _{stg}	-55 to 100	°C
Operating temperature		Ta	-20 to 85	°C	
Solderin	ng temperature (10 s			°C	
	Dielectric strength (AC for 1 min with ambient humidity of 60% (less) (see note)		V _{I-O}	2,500	V _{rms}

Note: Apply voltage between a group of pins 1, 2, and 3, 4 and that of pins 8, 7 and 6, 5.

■ Recommended Operating Conditions

Item	Symbol	Minimum	Typical	Maximum	Unit
Operating voltage	V_{DD}			280	V
Forward current	I _F	5.0	7.5	25	mA
Continuous load current	I _O			100	mA
Operating temperature	Та	-20		65	°C

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Input	LED forward current	V _F	I _F =10 mA	1.0	1.15	1.3	V
	Reverse current	I_R	V _R =5 V			10	μΑ
	Capacity between terminals	C _T	V=0, , f=1MHZ		30		pF
Output	Current leakage when the relay is open	I _{LEAK}	V _{OFF} =350 V			1	μΑ

■ Connection Characteristics (Ta = 25°C)

ltem	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Maximum resistance with	R _{ON}	I _{ON} =100 mA, I _F =10 mA		22	35	Ω
output ON		I _{ON} =20 to 100 mA, I _F =10 mA		26	40	

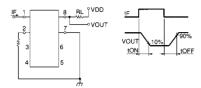
■ Insulation Characteristics (Ta = 25°C)

Item	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Floating capacity between I/O terminals	C _{I-O}	$V_S=0$, $f=1MH_Z$		0.8		pF
Insulation resistance	R _{I-O}	V _S =0, operating ambient humidity: ≦60%	5 x 10 ¹⁰	1014		Ω
Dielectric strength	V_{I-O}	AC for 1 min	2,500			V_{rms}
		AC for 1 s in oil		5,000		
		DC for 1 min in oil		5,000		V_{dc}

■ Switching Characteristics (Ta = 25°C)

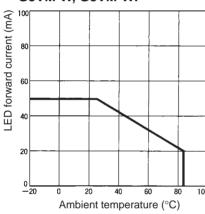
Item	Symbol	Measurement conditions	Minimum	Typical	Maximum	Unit
Turn-on time	t _{ON}	R _L =200 Ω V=20 V			1	ms
Turn-off time	t _{OFF}	V _{DD} =20 V, I _F =10 mA (see note)			1	

Note: Switching Time Measuring Circuit

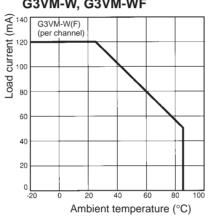


Engineering Data

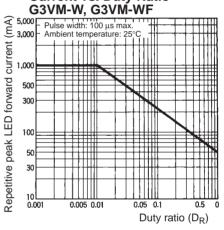
LED Forward Current vs. Ambient Temperature G3VM-W, G3VM-WF



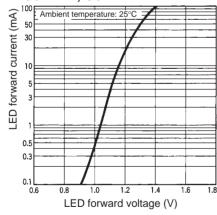
Load Current vs. Ambient Temperature Characteristics G3VM-W, G3VM-WF



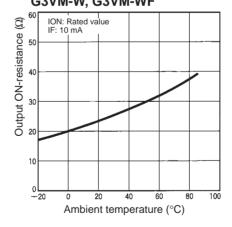
Repetitive Peak LED Forward Current vs. Duty Ratio



LED Forward Current vs. LED Forward Voltage G3VM-W, G3VM-WF



Output ON-resistance vs. Ambient Temperature G3VM-W, G3VM-WF

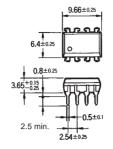


Dimensions

Note: All units are in millimeters unless otherwise indicated. G3VM-W

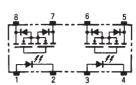


Note: "G3VM" is not printed on the actual product.

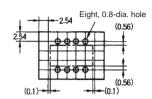


7.62±0.25 7.85~8.80

Terminal Arrangement/ Internal Connections (Top View)



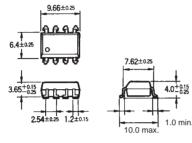
PCB Dimensions (Bottom View)



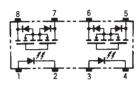
G3VM-WF



Note: "G3VM" is not printed on the actual product.



Terminal Arrangement/ Internal Connections (Top View)



Actual Mounting Pad Dimensions (Recommended Value, Bottom

